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**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re the Application of:

Geum-Jong BAE, et al

Art Unit: 2814

Serial No. 10/659,384  
(Division of Serial No. 10/274,035)

Examiner: H.V. Pham

Filed: September 11, 2003

*Confirmation No. 3795*

For: MOS TRANSISTOR HAVING A T-SHAPED  
GATE ELECTRODE AND METHOD FOR  
FABRICATING THE SAME

Attorney Docket No. 239/169 DIV

**AMENDMENT UNDER 37 C.F.R. § 1.116**

Mail Stop: Box AF  
Commissioner for Patents  
United States Patent and Trademark Office  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**INTRODUCTORY COMMENTS**

In response to the Office Action Made Final dated December 8, 2005, the following amendments and remarks are respectfully submitted in connection with the above-identified application:

**Amendments to the Claims** are reflected in a listing of claims, which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.